

Green Products

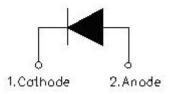
SUR1560 ULTRAFAST RECTIFIER

Applications:

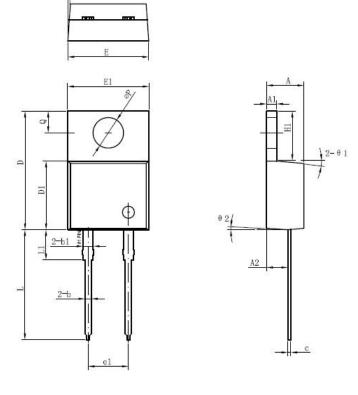
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm



Symbol	Dimensions in millimeters			
Syllibol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.55	8.07	8.85	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1		5.08		
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1		3.80		
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

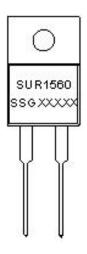
TO-220AC

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



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Marking Diagram:



Where XXXXX is YYWWL

SUR = Device Type

15 = Forward Current (15A) 60 = Reverse Voltage (600V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SUR1560	TO-220AC	50pcs / tube
	(Pb-Free)	Sopes / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	600	V
Average Forward Current	I _{F(AV)}	50% duty cycle @TC =100℃ rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	125	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 15A, Pulse, T _J = 25℃	2.4	V
	V _{F2}	@ 15A, Pulse, T _J = 100℃	2.0	V
Reverse Current*	I _{R1}	@V _R = rated VR	5	μΑ
		T _J = 25℃		
	I _{R2}	@V _R = rated VR	50	μΑ
		T _J = 100 ℃		
Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A,and I_m =250mA	50	ns

^{*} Pulse Width < 300 μ s, Duty Cycle <2%

Measured lead to lead 5 mm from package body

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	$^{\circ}\mathbb{C}$
Storage Temperature	T _{stg}	-	-55 to +150	$^{\circ}\mathbb{C}$
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	4.0	°C/W
Approximate Weight	wt	-	1.6	g
Case Style		TO-220AC		·



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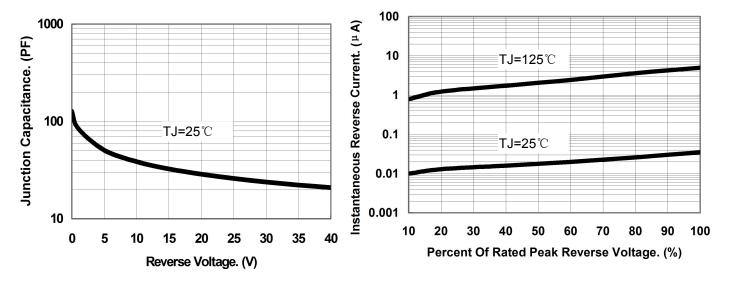


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

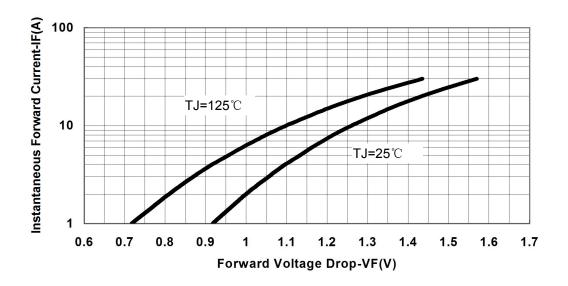


Fig.3-Typical Forward Voltage Drop Characteristics

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